

Silicon Diode

RGP10D

200V / 1A

DATASHEET

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Source: General Semiconductor Databook 1998

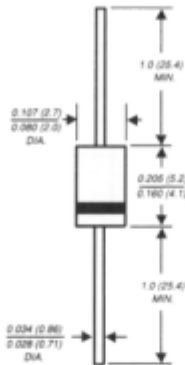
RGP10A THRU RGP10M

GLASS PASSIVATED JUNCTION FAST SWITCHING RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

PATENTED*

DO-204AL



NOTE: Lead diameter is 0.026 (0.66) / 0.023 (0.58) for suffix "1" part numbers

Dimensions in inches and (millimeters)

* Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306



FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ High temperature metallurgically bonded construction
- ◆ Glass passivated cavity-free junction
- ◆ Capable of meeting environmental standards of MIL-S-19500
- ◆ For use in high frequency rectifier circuits
- ◆ Fast switching for high efficiency
- ◆ 1.0 Ampere operation at T_A=55°C with no thermal runaway
- ◆ Typical I_r less than 0.1μA
- ◆ High temperature soldering guaranteed: 350°C/10 seconds 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-204AL molded plastic over glass body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.012 ounce, 0.3 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	RGP 10A	RGP 10B	RGP 10D	RGP 10G	RGP 10J	RGP 10K	RGP 10M	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at T _A =55°C	I _(AV)	1.0							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30.0							Amps
Maximum instantaneous forward voltage at 1.0A	V _F	1.3							Volts
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length T _A =55°C	I _R	100.0							μA
Maximum DC reverse current at rated DC blocking voltage T _A =25°C T _A =150°C	I _R	5.0 200.0							μA
Maximum reverse recovery time (NOTE 1)	t _{rr}	150			250		500		ns
Typical junction capacitance (NOTE 2)	C _J	15.0							pF
Typical thermal resistance (NOTE 3)	R _{θJA}	55.0							°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175							°C

NOTES:

- (1) Reverse recovery test conditions: I_r=0.5A, I_m=1.0A, I_m=0.25A
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

RATINGS AND CHARACTERISTIC CURVES RGP10A THRU RGP10M

